Photocouplers GaAlAs Infrared LED & Photo IC

TLP2761

1. Applications

- · Factory Networking
- · High-Speed Digital Interfacing for Instrumentation and Control Devices
- · I/O Interface Boards

2. General

The Toshiba TLP2761 consists of a high-output GaAlAs light-emitting diode coupled with integrated high gain, high-speed photodetectors. It is housed in the SO6L package.

This photocoupler guarantees operation at up to 125 °C and on supplies from 2.7 V to 5.5 V. Since TLP2761 has guaranteed 1 mA low supply current ($I_{\rm CCL}/I_{\rm CCH}$), and 1.6 mA ($T_{\rm a}$ = 125 °C) low threshold input current ($I_{\rm FHL}$), it contributes to energy saving of devices. It can drive directly from a microcomputer for a low input current.

The TLP2761 has an internal Faraday shield that provides a guaranteed common-mode transient immunity of $\pm 20~kV/\mu s$.

3. Features

- (1) Inverter logic type (Totem pole output)
- (2) Package: SO6L
- (3) Operating temperature: -40 to 125 °C
- (4) Supply voltage: 2.7 to 5.5 V
- (5) Data transfer rate: 15 MBd (typ.) (NRZ)
- (6) Threshold input current: 1.3 mA (max) (@ T_a = 105 °C) : 1.6 mA (max) (@ T_a = 125 °C)
- (7) Supply current: 1.0 mA (max)
- (8) Common-mode transient immunity: ±20 kV/μs (min)
- (9) Isolation voltage: 5000 Vrms (min)
- (10) Safety standards

UL-approved: UL1577, File No.E67349

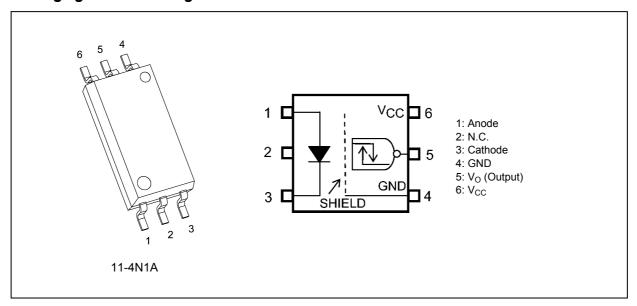
cUL-approved: CSA Component Acceptance Service No.5A File No.E67349

VDE-approved: EN60747-5-5, EN60065 or EN60950-1, EN62368-1 (Pending) (Note 1)

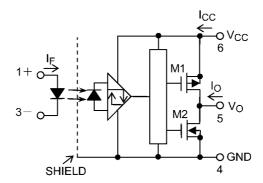
Note 1: When a VDE approved type is needed, please designate the Option (D4).



4. Packaging and Pin Configuration



5. Internal Circuit (Note)



Note: A 0.1- μF bypass capacitor must be connected between pin 6 and pin 4.

6. Principle of Operation

6.1. Truth Table

Input	LED	Output
Н	ON	L
L	OFF	Н

6.2. Mechanical Parameters

Characteristics	Min	Unit
Creepage distances	8.0	mm
Clearance distances	8.0	
Internal isolation thickness	0.4	



7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current		I _F		10	mA
	Input forward current derating	(T _a ≥ 110 °C)	$\Delta I_F/\Delta T_a$		-0.13	mA/°C
	Input forward current (pulsed)		I _{FP}	(Note 1)	40	mA
	Input forward current derating (pulsed)	(T _a ≥ 110 °C)	$\Delta I_{FP}/\Delta T_a$		-1.0	mA/°C
	Peak transient input forward current		I _{FPT}	(Note 2)	1	Α
	Peak transient input forward current derating	(T _a ≥ 110 °C)	$\Delta I_{FPT}/\Delta T_a$		-25	mA/°C
	Input power dissipation		P _D		20	mW
	Input power dissipation derating	(T _a ≥ 110 °C)	$\Delta P_D/\Delta T_a$		-0.5	mW/°C
	Input reverse voltage		V _R		5	V
Detector	Output current		Io		10	mA
	Output voltage		Vo		6	V
	Supply voltage		V _{CC}		6	
	Output power dissipation		Po		20	mW
	Output power dissipation derating	(T _a ≥ 110 °C)	$\Delta P_O/\Delta T_a$		-0.5	mW/°C
Common	Operating temperature		T _{opr}		-40 to 125	°C
	Storage temperature		T _{stg}		-55 to 125	
	Lead soldering temperature	(10 s)	T _{sol}		260	
	Isolation voltage	AC, 60 s, R.H. ≤ 60 %	BV _S	(Note 3)	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Pulse width (PW) \leq 1 ms, duty = 50 %
- Note 2: Pulse width (PW) \leq 1 μ s, 300 pps
- Note 3: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

8. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Input on-state current	I _{F(ON)}	(Note 1)	2	_	6	mA
Input off-state voltage	V _{F(OFF)}		0	_	0.8	٧
Supply voltage	V _{CC}	(Note 2)	2.7	3.3/5.0	5.5	
Operating temperature	T _{opr}	(Note 2)	-40	_	125	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this datasheet should also be considered.

Note: A ceramic capacitor (0.1 µF) should be connected between pin 6 and pin 4 to stabilize the operation of a highgain linear amplifier. Otherwise, this photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

- Note 1: The rise and fall times of the input on-current should be less than 0.5 µs.
- Note 2: Denotes the operating range, not the recommended operating condition.



9. Electrical Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C, V_{CC} = 2.7 to 5.5 V)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input forward voltage	V _F		_	I _F = 2 mA, T _a = 25 °C	1.35	1.50	1.65	V
Input forward voltage temperature coefficient	$\Delta V_F/\Delta T_a$		_	I _F = 2 mA	_	-2.0	_	mV/°C
Input reverse current	I _R		_	V _R = 5 V, T _a = 25 °C	_	_	10	μА
Input capacitance	Ct		_	V = 0 V, f = 1 MHz, T _a = 25 °C	_	20	_	pF
Low-level output voltage	V _{OL}		Fig.	$I_F = 2 \text{ mA}, I_O = 20 \mu\text{A}$	_	_	0.1	V
			12.1.1	I _F = 2 mA, I _O = 3.2 mA	_	0.12	0.4	
High-level output voltage	V _{OH}		Fig. 12.1.2	I_O = -20 μ A, V_F = 0.8 V, V_{CC} = 3.3 V	3.2	3.29	_	
				$I_O = -20 \mu A, V_F = 0.8 V,$ $V_{CC} = 5 V$	4.9	4.99	_	
				I_O = -3.2 mA, V_F = 0.8 V, V_{CC} = 3.3 V	2.3	3.15	_	
				I_O = -3.2 mA, V_F = 0.8 V, V_{CC} = 5 V	4.0	4.87	_	
Low-level supply current	I _{CCL}		Fig. 12.1.3	I _F = 2 mA	_	0.65	1.0	mA
High-level supply current	Іссн		Fig. 12.1.4	I _F = 0 mA	_	0.65	1.0	
Threshold input current (H/L)	I _{FHL}		_	I_{O} = 3.2 mA, V_{O} < 0.4 V, T_{a} = -40 to 105 °C	_	_	1.3	
				I _O = 3.2 mA, V _O < 0.4 V, T _a = -40 to 125 °C	_	_	1.6	

Note: All typical values are at V_{CC} = 5 V, T_a = 25 °C, unless otherwise noted.

10. Isolation Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz	_	0.4	_	pF
Isolation resistance	R _S	(Note 1)	V _S = 500 V, R.H. ≤ 60 %	1 × 10 ¹²	1014		Ω
Isolation voltage	BVS	(Note 1)	AC, 60 s	5000	_		Vrms
			AC, 1 s in oil	_	10000		
			DC, 60 s in oil		10000		Vdc

Note 1: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.



11. Switching Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C, V_{CC} = 2.7 to 5.5 V)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time (H/L)	t _{pHL}	(Note 1), (Note 3)	Fig. 12.1.5	$\begin{split} I_F &= 0 \rightarrow 2 \text{ mA, } R_T = 1.68 \text{ k}\Omega, \\ C_L &= 15 \text{ pF} \end{split}$		49	80	ns
Propagation delay time (L/H)	t _{pLH}	(Note 1), (Note 3)		I_F = 2 \rightarrow 0 mA, R_T = 1.68 k Ω , C_L = 15 pF		39	80	
Pulse width distortion	t _{pHL} -t _{pLH}	(Note 1), (Note 3)		I_F = 2 mA, R_T = 1.68 kΩ, C_L = 15 pF		10	25	
Propagation delay skew (device to device)	t _{psk}	(Note 1), (Note 2), (Note 3)		I_F = 2 mA, R_T = 1.68 k Ω , C_L = 15 pF	-30		30	
Fall time	t _f	(Note 1), (Note 3)		$\begin{split} I_F &= 0 \rightarrow 2 \text{ mA, } R_T = 1.68 \text{ k}\Omega, \\ C_L &= 15 \text{ pF} \end{split}$		3		
Rise time	t _r	(Note 1), (Note 3)		$\begin{split} I_F &= 2 \rightarrow 0 \text{ mA, } R_T = 1.68 \text{ k}\Omega, \\ C_L &= 15 \text{ pF} \end{split}$		3	1	
Common-mode transient immunity at output high	CM _H	(Note 3)	Fig. 12.1.6	$\begin{split} &V_{CM} = 1000 \ V_{p\text{-}p}, \\ &I_{F} = 0 \ \text{mA}, \ V_{CC} = 3.3 \ \text{V} \ / \ 5 \ \text{V}, \\ &T_{a} = 25 \ ^{\circ}\text{C}, \ R_{T} = 1.68 \ \text{k}\Omega \end{split}$	±20	±25	_	kV/μs
Common-mode transient immunity at output low	CM _L	(Note 3)		V_{CM} = 1000 V_{p-p} , I_F = 2 mA, V_{CC} = 3.3 V / 5 V, T_a = 25 °C, R_T = 1.68 k Ω	±20	±25	_	

Note: All typical values are at $T_a = 25$ °C.

Note 1: f = 5 MHz, duty = 50 %, input current $t_r = t_f = 5$ ns, C_L is approximately 15 pF which includes probe and stray wiring capacitance.

Note 2: The propagation delay skew, t_{psk} , is equal to the magnitude of the worst-case difference in t_{pHL} and/or t_{pLH} that will be seen between units at the same given conditions (supply voltage, input current, temperature, etc).

Note 3: $R_T = R_1 + R_2 = 1.68 \text{ k}\Omega$

Recommendation input resistance conditions : R_1 = R_2 = 840 Ω

TLP2761

12. Test Circuits and Characteristics Curves

12.1. Test Circuits

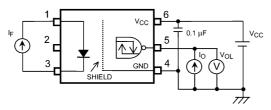


Fig. 12.1.1 V_{OL} Test Circuit

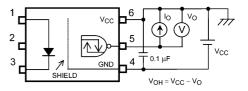


Fig. 12.1.2 V_{OH} Test Circuit

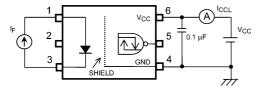


Fig. 12.1.3 I_{CCL} Test Circuit

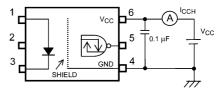
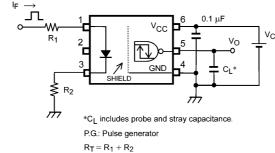


Fig. 12.1.4 I_{CCH} Test Circuit

 $I_F=2~mA~(P.G.) \label{eq:free_f}$ (f = 5 MHz, duty = 50 %, t_f = t_f = less than 5 ns)



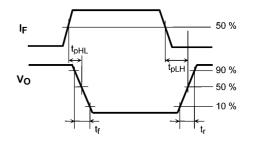


Fig. 12.1.5 Switching Time Test Circuit and Waveform

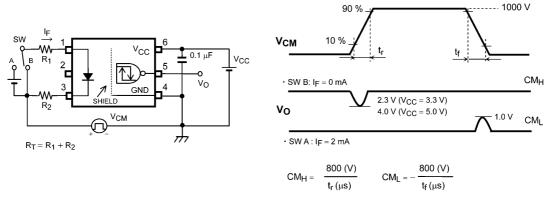


Fig. 12.1.6 Common-Mode Transient Immunity and Waveform



13. Soldering and Storage

13.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

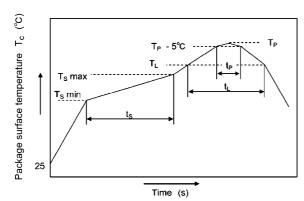
When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



	Symbol	Min	Max	Unit
Preheat temperature	Ts	150	200	ů
Preheat time	ts	60	120	S
Ramp-up rate (T _L to T _P)			3	°C/s
Liquidus temperature	TL	2	°C	
Time above T _L	tL	60	150	S
Peak temperature	T _P		260	°C
Time during which T_c is between ($T_P - 5$) and T_P	t _P		30	s
Ramp-down rate (T _P to T _L)			6	°C/s

Fig. 13.1.1 An Example of a Temperature Profile When Lead(Pb)-free Solder Is Used

· When using soldering flow

Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds. Mounting condition of 260 °C within 10 seconds is recommended.

Flow soldering must be performed once.

· When using soldering Iron

Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C

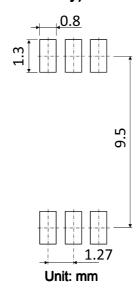
Heating by soldering iron must be done only once per lead.

13.2. Precautions for General Storage

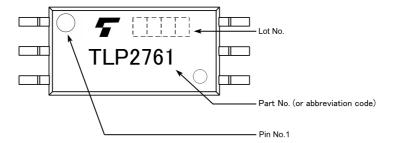
- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45 % to 75 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- · When restoring devices after removal from their packing, use anti-static containers.
- · Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.



14. Land Pattern Dimensions (for reference only)



15. Marking





16. EN60747-5-5 Option (D4) Specification

• Part number: TLP2761 (Note 1)

• The following part naming conventions are used for the devices that have been qualified according to option (D4) of EN60747.

Example: TLP2761(D4-TP,E(T

D4: EN60747 option TP: Tape type

E: [[G]]/RoHS COMPATIBLE (Note 2)

Domestic ID (Country/Region of origin: Thailand): (T

Note 1: Use TOSHIBA standard type number for safety standard application.

e.g., TLP2761(D4-TP,E(T \rightarrow TLP2761

Note 2: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

Description	Symbol	Rating	Unit
Application classification			
for rated mains voltage \leq 600 Vrms for rated mains voltage \leq 1000 Vrms		I-IV I-III	_
Climatic classification		55 / 125 / 21	_
Pollution degree		2	_
Maximum operating insulation voltage	VIORM	1230	Vpeak
Input to output test voltage, Method A V_{pr} = 1.6 × V_{IORM} , type and sample test t_p = 10 s, partial discharge < 5 pC	V _{pr}	1970	Vpeak
Input to output test voltage, Method B $V_{pr} = 1.875 \times V_{IORM}, 100 \% \text{ production test}$ $t_p = 1 \text{ s, partial discharge} < 5 \text{ pC}$	V _{pr}	2310	Vpeak
Highest permissible overvoltage (transient overvoltage, t _{pr} = 60 s)	V _{TR}	8000	Vpeak
Safety limiting values (max. permissible ratings in case of fault, also refer to thermal derating curve) current (input current I _F , P _{SO} = 0) power (output or total power dissipation) temperature	I _{si} P _{so} T _s	250 400 150	mA mW °C
Insulation resistance V_{IO} = 500 V, T_a = 25 °C V_{IO} = 500 V, T_a = 100 °C V_{IO} = 500 V, T_a = T_s	R _{si}	≥ 10 ¹² ≥ 10 ¹¹ ≥ 10 ⁹	Ω

Fig. 16.1 EN60747 Isolation Characteristics



Minimum creepage distance	Cr	8.0 mm
Minimum clearance	Cl	8.0 mm
Minimum insulation thickness	ti	0.4 mm
Comparative tracking index	СТІ	175

Fig. 16.2 Insulation Related Specifications (Note)

Note: This photocoupler is suitable for **safe electrical isolation** only within the safety limit data.

Maintenance of the safety data shall be ensured by means of protective circuits.



Fig. 16.3 Marking on Packing for EN60747

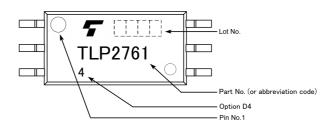
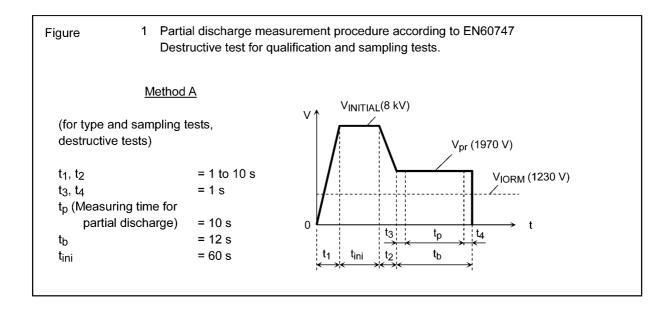
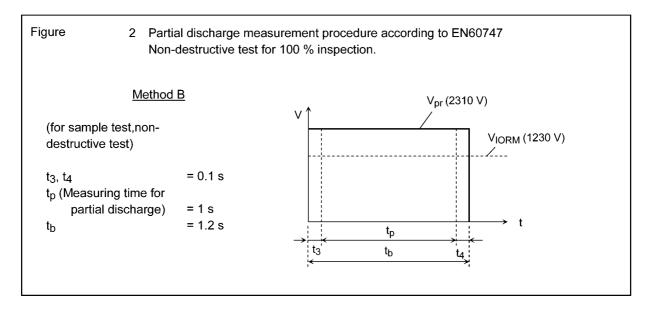


Fig. 16.4 Marking Example (Note)

Note: The above marking is applied to the photocouplers that have been qualified according to option (D4) of EN60747.







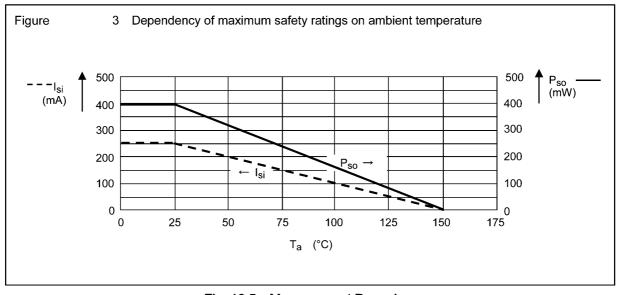


Fig. 16.5 Measurement Procedure



17. Embossed-Tape Packing (TP) Specification for Mini-Flat Photocouplers

17.1. Applicable Package

Package Name	Product Type
SO6L	Long creepage mini flat coupler

17.2. Product Naming Conventions

When placing an order, please specify the part number, tape type and quantity as shown in the following example.

Example) TLP2761(TP,E(T

Part number: TLP2761
Tape type: TP(12mm pitch)

[[G]]/RoHS COMPATIBLE: E (Note)

Domestic ID(Country/Region of origin:Thailand):(T

Note: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

17.3. Tape Dimensions Specification

Specification	Division	Packing Amount (A unit per reel)
TP	_	1500

17.3.1. Orientation of Device in Relation to Direction of Feed

Device orientation in the carrier cavities as shown in the following figure.

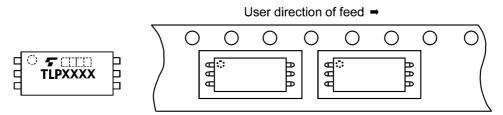


Fig. 17.3.1.1 Orientation of Device in Relation to Direction of Tape Movement

17.3.2. Empty Device Recesses

Characteristics	Standard	Remarks
Occurrences of 2 or more successive empty cavities	0 device	Within any given 40-mm section of tape, not including leader and trailer
Single empty cavity	6 devices (max) per reel	Not including leader and trailer

17.3.3. Tape Leader and Trailer

The start of the tape has 14 or more empty holes. The end of the tape has 34 or more empty holes and more than 30mm only for a cover tape.



17.3.4. Tape Dimensions

Tape material: Plastic (for protection against static electricity)

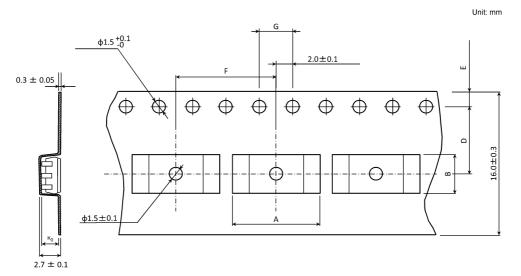


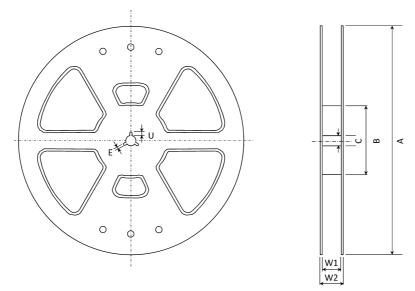
Table Tape Dimensions (unit: mm, tolerance: ±0.1)

Symbol	Dimension	Remark
А	10.4	_
В	4.24	_
D	7.5	Center line of embossed cavity and sprocket hole
E	1.75	tance between tape edge and sprocket hole center
F	12.0	Cumulative error +0.1/-0.3 (max) per 10 empty cavities holes
G	4.0	Cumulative error +0.1/-0.3 (max) per 10 sprocket holes
K ₀	2.4	Internal space



17.3.5. Reel Specification

Material: Plastic (for protection against static electricity)



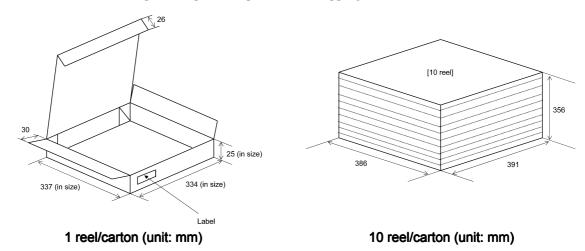
Reel Forms

Table Reel Dimensions (unit: mm)

Symbol	Dimension
Α	φ330 ± 2
В	φ100 ± 1
С	φ13 ± 0.5
E	2.0 ± 0.5
U	4.0 ± 0.5
W1	17.4 ± 1.0
W2	21.4 ± 1.0

17.4. Packing (Note)

Either one reel or ten reels of photocouplers are packed in a shipping carton.



Note: Taping reel diameter: \$\phi 330 mm

17.5. Label Format

- (1) Carton: The label provides the part number, quantity, lot number, the Toshiba logo, etc.
- (2) Reel: The label provides the part number, the taping name, quantity, lot number, etc.



17.6. Ordering Information

When placing an order, please specify the part number, tape type and quantity as shown in the following example.

Example) TLP2761(TP,E 1500pcs

Part number: TLP2761 Tape type: TP(12mm pitch)

[[G]]/RoHS COMPATIBLE: E (Note)
Quantity (must be a multiple of 1500pcs)

Note: Please contact your Toshiba sales representative for details on environmental information such as the product's

RoHS compatibility.

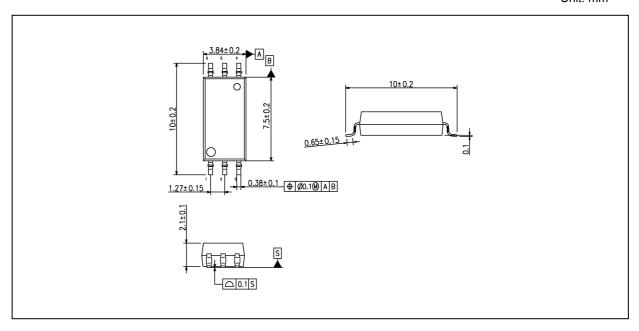
RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the

restriction of the use of certain hazardous substances in electrical and electronics equipment.



Package Dimensions

Unit: mm



Weight: 0.126 g (typ.)

	Package Name(s)
TOSHIBA: 11-4N1A	



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